Amendments to the Claims:

1-14. (Cancelled)

15. (Currently Amended) A method for testing memory, said method comprising:

performing a first test, wherein functional memory is tested;

repairing the functional memory by adding access to redundant elements, thereby

providing repaired functional memory;

performing a second test, wherein the repaired functional memory is tested:

after repairing the functional memory and after testing the repaired functional

memory, adding access to redundant memory not required for repair of the functional memory:

and

after testing the repaired functional memory and then adding access to redundant memory

not required for repair of the functional memory, performing a third test, wherein the redundant

memory is tested, wherein the step of adding access to redundant memory which is not required

for the repair comprises faking defects to remap good elements with redundant elements.

16. (Previously Presented) A method as recited in claim 15, further comprising using repair

information to repair the functional memory.

17. (Previously Presented) A method as recited in claim 15, wherein the step of adding access

to redundant memory which is not required for the repair comprises forcing usage of redundant

elements which are not needed to be used for repairing the functional memory.

18. (Cancelled)

19. (Previously Presented) A method as recited in claim 15, further comprising checking

interaction between redundant elements of the memory which are not used and adjacent

functional memory.

20. (Previously Presented) A method as recited in claim 15, wherein the step of adding access

to redundant memory not required for repair of the functional memory comprises adding access

to all remaining redundant memory, and wherein the step of performing a third test comprises

testing all the remaining redundant memory.

21. (Currently Amended) A mode for testing memory, said mode comprising:

means for performing a first test, wherein functional memory is tested;

repairing the functional memory by adding access to redundant elements thereby

providing repaired functional memory;

means for performing a second test, wherein the repaired functional memory is tested;

Serial No. 10/701,332 Art Unit: 2117 means for, after repairing the functional memory and after testing the repaired functional

memory, adding access to redundant memory not required for repair of the functional memory by

faking defects to remap good elements with redundant elements; and

means for, after testing the repaired functional memory and then adding access to

redundant memory not required for repair of the functional memory, performing a third test,

wherein the redundant memory is tested.

22. (Previously Presented) A mode as recited in claim 21, further comprising means for using

repair information to repair the functional memory.

23. (Previously Presented) A mode as recited in claim 21, further comprising means for

forcing usage of redundant elements which are not needed to be used for repairing the functional

memory.

(Cancelled)

25. (Previously Presented) A mode as recited in claim 21, further comprising means for

checking interaction between redundant elements of the memory which are not used and adjacent

functional memory,

Serial No. 10/701,332 Art Unit: 2117 26. (Previously Presented) A mode as recited in claim 21, wherein the means for adding access to redundant memory not required for repair of the functional memory comprises means for adding access to all remaining redundant memory, and wherein the means for performing a third test comprises means for testing all the remaining redundant memory.